

Logic-in-memory computation using magnetic skyrmions

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- Logic-in-memory
- Skyrmion motion in ion irradiated films
- Skyrmions in Synthetic Antiferromagnets
- 1-bit Full Adder
- Cascading and reconfigurability
- Hybrid Demultiplexers

Skyrmions as memory & logic element

FM Skyrmion

- > Nanometer scale
- Chiral and topologically protected
- Fast manipulation by electric current







Challenges

- Information is encoded as distance b/w skyrmions -> can change with thermal noise
- No interconversion of magnetic to electrical signal or vice versa
- Easy cascading
- Reconfigurability for programmable logic

[1] Nat. Nano. 8, 839–844 (2013) ; [2] Phys. Rev. Applied 12, 064053 (2019)

Skyrmion-barrier dynamics

Ion-irradiation for



Uniformly irradiated FM



Skyrmion Hall effect is present

(θ_{SH}=62°)

R. Juge *et al.*, Nano Lett., 21, 2989–2996 (2021)

Skyrmion-barrier dynamics

Ion-irradiation for



Irradiated FM with a thin

non-irradiated barrier



Skyrmion crossover

through barrier

R. Juge *et al.*, Nano Lett., 21, 2989–2996 (2021)

Skyrmion-barrier dynamics

Ion-irradiation for

skyrmion guiding

R. Juge et al., Nano Lett., 21, 2989-2996 (2021)

Irradiated FM with a thick

non-irradiated barrier



New degree of freedom : Tunability of anisotropy barriers opens-up possibility to manipulate skyrmion trajectory for logic and computation

Skyrmions in Synthetic Antiferromagnets (FM/spacer/FM)



Skyrmion based racetrack memory by confining skyrmions



1-Bit Full Adder (FA) design





2 Sk input : Skyrmions repel each other and are collected in carry output (Sum=0, C_{out}=1)

3 Sk input : All 3 skyrmions move towards 3 outputs (Sum=1, C_{out}=1)

3-bit ripple carry FA with cascading





- Straightforward to cascade
- Synchronization can be implemented with "Sync-in" and "Sync-out" logic elements

3-Bit FA without cascading



 H_K (cells)< H_K (Shaded) H_K (barrier)



Negative polarity

pulse applied

- Modification of barriers allows individual control over outputs
- Reduced design complexity as no cascading is required for multi-bit FA operations
- Synchronization is supported intrinsically by design and does not require any extra logic elements

Comparing 3-Bit FA with and w/o cascading





- In the w/o cascaded version, the device area is independent of number of bits
- Sending the carry-out back to input stage in w/o cascaded design, an extra delay is introduced which nearly doubles the operation time
- As number of bits increase, w/o cascaded design consumes significantly less energy

Reconfigurability



NOT/BUFFER Gate A A Ā 0 A **XOR/AND** Gate XNOR/OR Gate $A \cdot B$ A A + BA $A \odot B$ $A \oplus B$ $\mathbf{0}$ B В $A \cdot B$ A + B

By fixing inputs, FA can be reconfigured to perform several other logic operations including NAND gate



Electrical Tolerances



At minimum, 10% variation in amplitude of electrical current is allowed for all pulses (even higher tolerance for J₂)

~30% variation in the pulse width is allowed for all current pulses

N. Sisodia, et al., "Robust programmable logic-in-memory skyrmion device using local energy barriers" (Phys. Rev. Applied 18, 014025 (2022))

Skyrmion based 1-to-2 demultiplexer

Demultiplexer

→selector input switches the output path





Dmux: Type A

→Sk-Sk repulsion enhances tunnelling →Selector input X_1 track is below G



Dmux: Type B

 \rightarrow Sk-Sk repulsion blocks tunnelling \rightarrow Selector input X₁ track is above G

$$X_1 = 0 \qquad \overline{X_1} = 1$$

G=1
$$X_1 = 0$$

$$X_1 = 1$$

$$\overline{X_1} = 0$$

$$X_1 = 1$$

Universal logic based on cascaded demultiplexers



N. Sisodia, et al.,"Programmable skyrmion logic gates based on skyrmion tunneling" (Phys. Rev. Applied 17, 064035 (2022))

What next?

- Focus on techniques which utilize the collective dynamic behaviour of skyrmions \rightarrow reservoir computing
- Higher level modelling needed for complex/large scale circuits
 - N. Sisodia, et al., "Robust programmable logic-in-memory skyrmion device using local energy barriers" Phys. Rev. Applied 18, 014025 (2022)

Related

publications \rightarrow

- N. Sisodia, et al., "Programmable skyrmion logic gates based on skyrmion tunneling" Phys. Rev. Applied 17, 064035 (2022)
 - R. Juge, N. Sisodia, et al., Skyrmions in synthetic antiferromagnets and their nucleation via electrical current and ultra-fast laser illumination
 Nat. Commun. 13, 4807 (2022))
 - R. Juge, et al., Helium Ions Put Magnetic Skyrmions on the Track Nano Lett., 21, 2989–2996 (2021)



Thank you for your attention !

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